

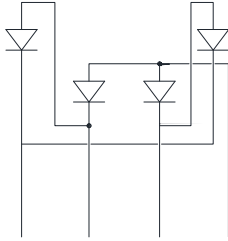
Bridge Rectifiers

Features

- UL recognition, file #E230084
- Glass passivated chip junction
- Thin single in-line package
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.



Mechanical Data

- **Package:** PB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■Maximum Ratings (T_a=25 Unless otherwise specified

PARAMETER		SYMBOL	UNIT	PB5010H
Device marking code				PB5010H
Maximum Repetitive Peak Reverse Voltage		VRRM	V	1600
Maximum RMS Voltage		VRMS	V	1120
Maximum DC blocking Voltage		VDC	V	1600
Average rectified output current @60Hz sine wave, R-load,	With heatsink Tc =90	IO	A	50.0
	Without heatsink Ta =25			4.5
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25		IFSM	A	500
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25				1000
Current squared time @1ms≤t≤8.3ms Tj=25 , Rating of per diode		I²t	A²s	1037.5
Storage temperature		Tstg		-55 ~ +150
Junction temperature		Tj		-55 ~ +150
Dielectric strength @ Terminals to case, AC 1 minute		Vdis	KV	2.5
Mounting torque @Recommend torque 5kg cm		Tor	kg cm	8

■Electrical Characteristics T_a=25 Unless otherwise specified

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	PB5010H
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =25.0A	1.1
Maximum DC reverse current at rated DC blocking voltage per diode	I _R	μA	T _j =25	5
			T _j =125	1000
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	195



PB5010H

■ Thermal Characteristics $T_a=25$ Unless otherwise specified

PARAMETER		SYMBOL	UNIT	PB5010H
Thermal Resistance	Between junction and ambient, Without heatsink	$R_{\theta JA}$	/W	15.0
	Between junction and case, With heatsink	$R_{\theta JC}$		0.6

Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
PB5010H	B1	Approximate 7.5	15	750	1500	TUBE

■ Characteristics (Typical)

FIG1: I_o - T_c Curve

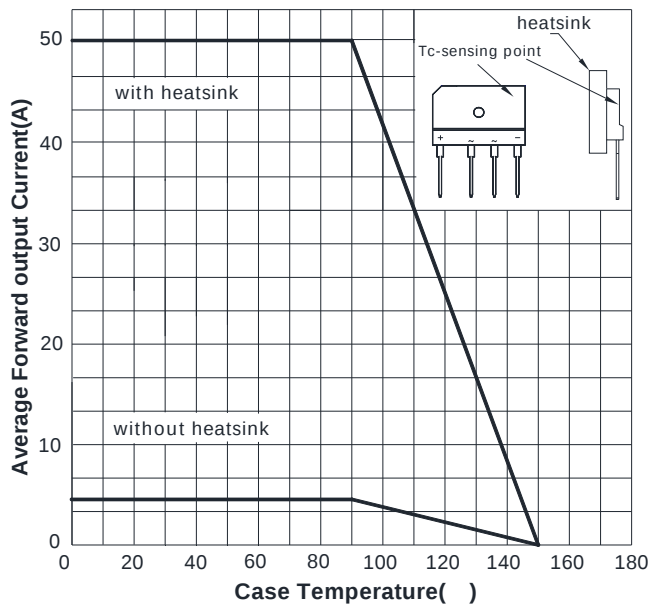


FIG2: Surge Forward Current Capability

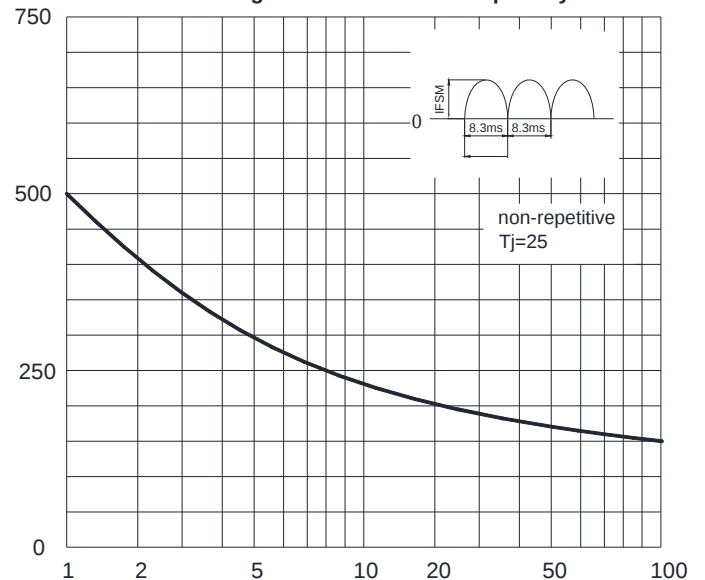


FIG3: Typical Forward Voltage

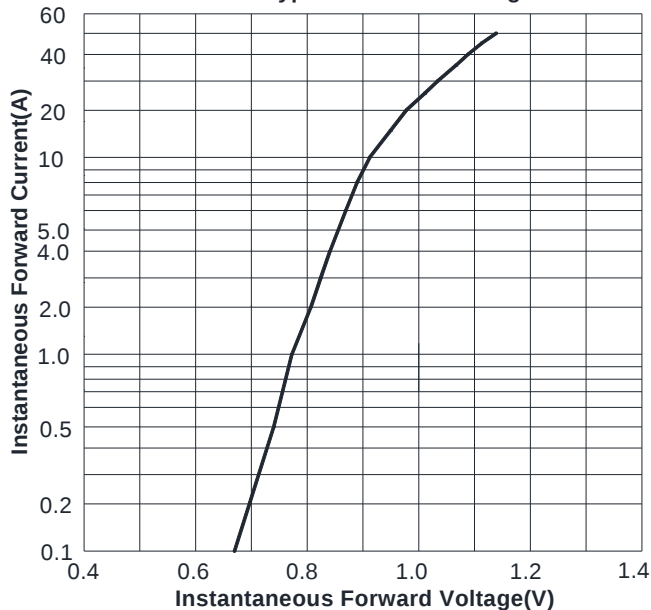
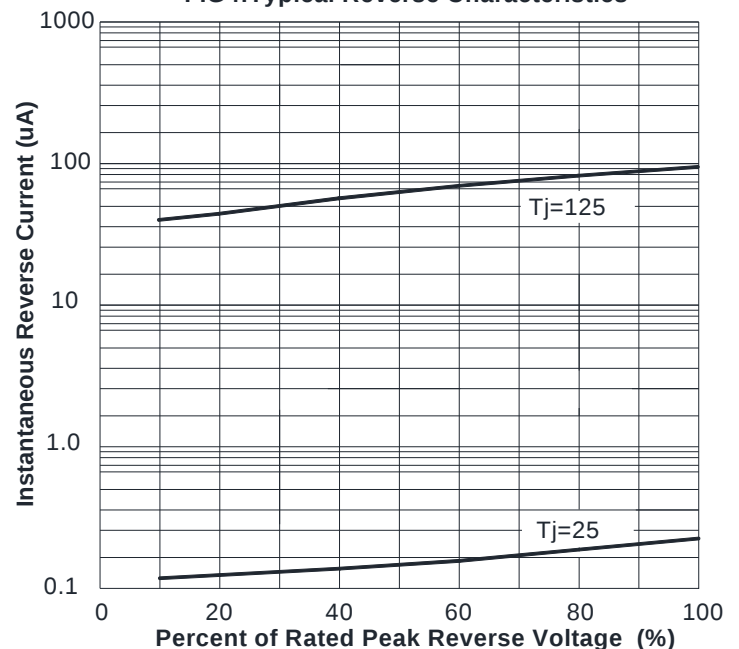
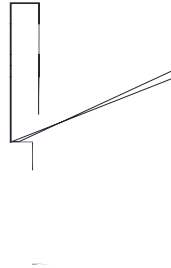
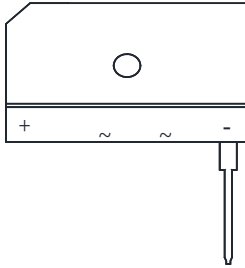


FIG4: Typical Reverse Characteristics





■ Outline Dimensions



PB		
Dim	Min	Max
A	29.7	30.3
B	19.7	20.3
C	17.0	18.0
D	4.8	5.8
E	3.8	4.2
F	7.3	7.7
G	9.8	10.2
H	0.9	1.1
I	2.0	2.4
J	2.3	2.7
K	3.4	3.8
L	4.4	4.8
M	10.8	11.2
N	3.1	3.7
O	3.1	3.4
P	0.6	0.8
A1	28.75	29.15
B1	18.75	19.15
C1	0.3	0.7
D1	0.3	0.7

Dimensions in millimeters



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